

FRED Pt® Gen 4 Doubler Ultrafast Diode, 600 A (INT-A-PAK Power Modules)



PRIMARY CHARACTE	IMARY CHARACTERISTICS				
V_R	600 V				
I _{F(AV)} at T _C	600 A at 25 °C				
t _{rr} at 25 °C	150 ns				
Туре	Modules - diode, FRED Pt®				
Package	INT-A-PAK				
Circuit configuration	Diode doubler circuit				

FEATURES

- Gen 4 FRED Pt® dices technology
- Ultrasoft reverse recovery characteristics
- Low I_{RRM} and reverse recovery charge
- · Very low forward voltage drop
- 175 °C operating junction temperature
- UL approved file E78996 for application with maximum case temperature up to 140 °C
- Large creepage distances
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

Gen 4 FRED Pt technology, state of the art, ultra low V_F , soft switching optimized for IGBT F/W diode.

The minimized conduction loss, optimized storage charge, and low recovery current, minimized the switching losses and reduce the over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RAT	INGS	3		
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_{R}		600	V
Continuous forward current		T _C = 25 °C	771	
Continuous forward current	I _F	T _C = 63 °C	640	A
Single pulse forward current	I _{FSM}	t_p = 10 ms, 50 Hz, sine half wave, initial T_J = 175 °C	4140	
Maximum navvar dissination	D	T _C = 25 °C	1923	W
Maximum power dissipation	P_{D}	T _C = 90 °C	1090	- vv
Operating junction temperature range	TJ		-40 to +175	°C
Storage temperature range	T _{Stg}		-40 to +150]
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted, t = 1 s	3500	V

ELECTRICAL SPECIFICATION	NS (T _J = 2	5 °C unless otherwise specified	d)			
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 500 μA	600	-	-	
		I _F = 300 A	-	1.305	-	
Forward voltage drop	V	I _F = 600 A	-	1.60	1.77	V
Forward voltage drop	V_{FM}	I _F = 300 A, T _J = 150 °C	-	1.08	-	1
		I _F = 600 A, T _J = 150 °C	-	1.47	-	
Reverse leakage current	1	V _R = 600 V	-	13	-	μA
neverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V	-	3.2	-	mA



DYNAMIC RECOVERY	ERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	+	T _J = 25 °C		-	150	-	20
heverse recovery time	t _{rr}	T _J = 125 °C		-	310	-	ns
Pools recovery current		T _J = 25 °C	l _F = 150 A dl/dt = 200 A/μs	-	14	-	А
Peak recovery current	I _{rr}	T _J = 125 °C	$V_{R} = 400 \text{ V}$	-	33	-	_ ^
Reverse recovery charge	0	T _J = 25 °C	""	-	1.65	-	μC
heverse recovery charge	Q _{rr}	T _J = 125 °C		-	7.03	-	

THERMAL -	MAL - MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum therma	,	R _{thJC}	DC operation	0.088	K/W
Typical thermal r		R _{thCS}	Mounting surface, flat, smooth and greased	0.035	
Mounting	to heat sink		A mounting compound is recommended and the		
torque ± 10 %	busbar		torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6	Nm
Approximate we	iaht			200	g
Approximate we	igrit			7.1	OZ.
Case style				INT-A-PAK	

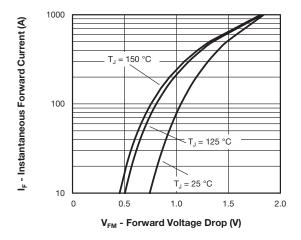


Fig. 1 - Typical Forward Voltage Drop Characteristics

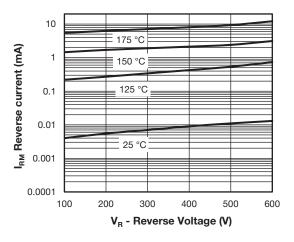


Fig. 2 - Typical Value of Reverse Current vs. Reverse Voltage

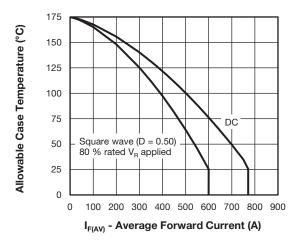


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

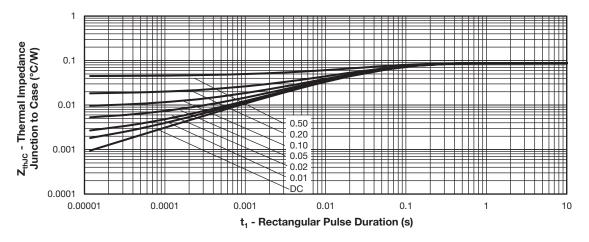


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

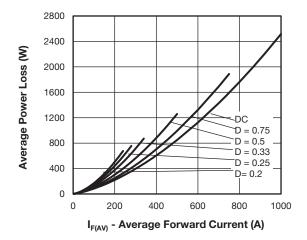


Fig. 5 - Forward Power Loss Characteristics

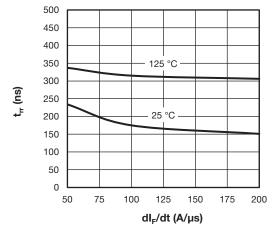


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 400 \text{ V}$

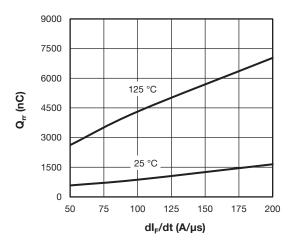


Fig. 7 - Typical Reverse Recovery Charge vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 400 \text{ V}$

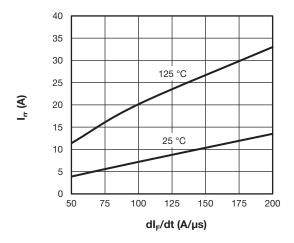
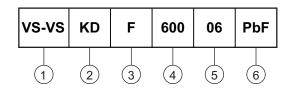


Fig. 8 - Typical Reverse Recovery Current vs. dI_F/dt I_{FM} = 150 A, V_R = 400 V

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration: KD = doubler circuit

F = FRED Pt® ultrafast diode

- Current rating (600 = 600 A)

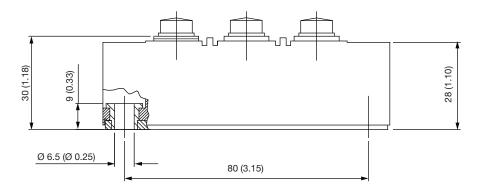
- Voltage rating (06 = 600 V)

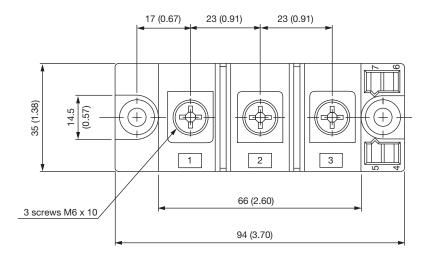
6 - PbF = lead (Pb)-free

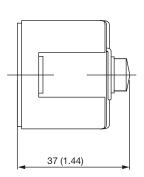
CIRCUIT CONFIGURATION			
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING	
Diode doubler circuit	KD	KD reversed polarity	



DIMENSIONS in millimeters (inches)



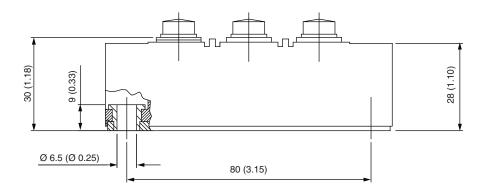


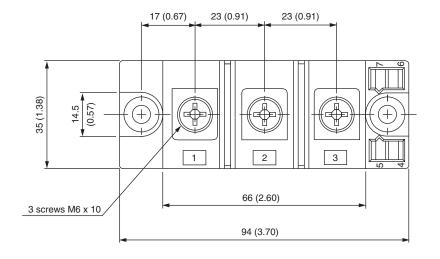


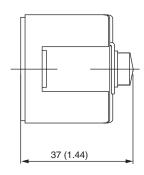


INT-A-PAK DBC

DIMENSIONS in millimeters (inches)









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